METALLIC WIRE SUBSTRATE (MWS) MICROSTRIP STRUCTURE: CHARACTERIZATION AND APPLICATION TO A PATCH ANTENNA

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ABSTRACT

This paper presents the characterization of the novel metallic wire substrate (MWS) introduced in [1] and its application to a microstrip patch antenna. It is shown numerically that the MWS exhibits artificial magneto-dielectric properties with simultaneously enhanced effective permittivity and permeability over a large frequency band. Consequently, due to the higher effective refractive index, the effective wavelength is reduced which implies reduction in the size of the elements printed on the MWS. First, the MWS microstrip line is analyzed and a procedure for its effective constitutive parameters ($\varepsilon$, $\mu$) extraction is described and a parametric analysis is carried out to show the range of $\varepsilon$, $\mu$ values achievable with typical substrates. Then, a patch antenna with reduced size is demonstrated, discussed in terms of efficiency, gain and compared to a homogeneous substrate.

1. INTRODUCTION

Artificial dielectrics consist of subwavelength conducting obstacles embedded in a homogeneous host medium [2]. After their introduction by Kock in 1948 [3], artificial dielectrics were investigated both theoretically and experimentally by several researchers in the 1950s [4-8].

Recently, a novel metallic wire substrate (MWS) was introduced as an artificial dielectric with specific properties for planar microwave circuits [1,9]. These properties include magneto-dielectric characteristics, i.e. simultaneously enhanced effective permittivity and permeability (para-electric and para-magnetic response). This lead to enhanced effective refractive index or reduction of effective guided wavelength, and consequently provide reduction in the size of the circuits. A similar structure was recently presented in [10]. Other magneto-dielectric substrates were discussed by Mossallaei in [11,12]; these substrate exhibit interesting characteristics at the expense of the drawbacks of narrow bandwidth (due to their resonant nature), and complex, bulky non-MMIC compatible architecture.

This paper presents a parametric analysis of the metallic wire substrate (MWS) microstrip and its application to a microstrip patch antenna with reduced size with consideration efficiency.

2. METALLIC WIRE SUBSTRATE (MWS) MICROSTRIP TRANSMISSION LINE

2.1. Description of the structure

Fig. 1(a) shows a microstrip transmission line (TL) printed on a metallic wire substrate (MWS). This MWS is constituted of a dense mesh of metallic wires in a conventional homogeneous substrate. The metallic wires are copper plated via holes with interspacing much smaller than the guided wavelength $\lambda_g$ so as to build an effective medium. In order to prevent short-circuiting contacts, a thin isolating substrate layer is placed between the TL and the MWS as shown in Fig. 1(b).

The MWS prototype is shown in Fig. 2(a). The host substrate of the array of metallic wires is Duroid 6002 with dielectric constant $\varepsilon_r$ of 2.94, loss tangent $\tan\delta$ of 0.0012 at 10 GHz and thickness $h_2$ of 0.508 mm. The wire mesh is made of copper plated via holes having diameter $d$ of 0.381 mm using a laser-drilling and holes plating technology available at the Poly-Grames...
Research Center (www.grames.polymtl.ca). The spacing between adjacent via holes is of 0.635 mm (center to center). The MWS contains an array of 200 x 200 via holes. The backplane of the MWS is also copper plated to create a ground plane. The thin isolating substrate is also Duroid 6002 with thickness $h_1$ of 0.508 mm.

Figure 2. MWS microstrip transmission line (TL) prototype.

As shown in Fig. 2(b), a microstrip transmission line (TL) with a width of 2.54 mm for 50 $\Omega$ characteristic impedance and a length of 48 mm is etched on the isolation layer. This substrate is necessary to prevent short circuit between the TL and the ground.

### 2.2. S-parameters

The MWS microstrip TL prototype shown in Fig. 2 was measured and compared to a microstrip TL on a regular Duroid 6002 substrate with the same length and width. The S-parameters of these two TLs from DC to 20 GHz are shown in Fig. 3.

As shown in Fig. 3(a), good matching (low insertion loss) throughout the measured frequency range is achieved. It may be seen form its larger phase shift that the propagation constant $\beta$ in the MWS structure has been increased compared to its value in the regular Duroid substrate as a consequence of the loading effect of the via. That indicates that the MWS has a higher refractive index $n$ or, equivalently, exhibits slow-wave characteristics.

### 2.3. Extraction of effective parameters

In this section, we extract the transmission line parameters of the microstrip MWS structure to compute its effective parameters $\varepsilon_{eff}$ and $\mu_{eff}$. The propagation constant $\beta$ and input impedance $Z_{in}$ of a TL are [13]

$$\beta = -\frac{\theta}{l} = -\frac{\text{unwrapped}[\text{phase}(S_{21})]}{l}, \quad (1)$$

$$Z_{in} = Z_0 \frac{Z_L + jZ_0 \tan(\beta l)}{Z_0 + jZ_L \tan(\beta l)}, \quad (2)$$

where $Z_L=50\Omega$ is the impedance of the load. By combining (1) and (2) and using the measured S-parameters, the effective propagation constant $\beta$ and characteristic impedance $Z_0$ of the MWS TL can be readily obtained.

The propagation constant $\beta$ can also be expressed as a function of the host medium parameters and the free space wave number $k_0$ as

$$\beta = n k_0 = \sqrt{\varepsilon_{eff} \mu_{eff}} k_0, \quad (3)$$
In the most general case of a magneto-dielectric substrate, the formula for the conventional microstrip TL characteristic impedance needs to be generalized to include the contribution of the effective permeability

\[
Z_0 = \sqrt{\frac{\mu_{\text{eff}}}{\varepsilon_{\text{eff}}}} \left[ \frac{120}{W} \right] \left( W/(h_1 + h_2) + \frac{1.393 + 0.667 \ln[W/(h_1 + h_2) + 1.444]}{W} \right)
\]

(4)

Combining (3) and (4), the following expressions are obtained for the effective permittivity \(\varepsilon_{\text{eff}}\) and permeability \(\mu_{\text{eff}}\) after simple algebraic manipulations

\[
\mu_{\text{eff}} = \xi Z_0 \frac{\beta}{120\pi k_0},
\]

(5)

\[
\varepsilon_{\text{eff}} = \frac{1}{\xi} \frac{120\pi \beta}{Z_0 k_0},
\]

(6)

where

\[
\xi = \frac{W}{(h_1 + h_2)} + 1.393 + 0.667 \ln \left[ W/(h_1 + h_2) + 1.444 \right]
\]

(7)

Fig. 4 shows the effective parameters of the MWS TL prototype compared to those of a MoM-simulated 50\(\Omega\) transmission line on a regular substrate computed by (5) and (6).

Good agreement between the MoM-simulation and the measurements results is observed. The MoM simulation model can therefore be used for the characterization of the metallic wire substrate (MWS), which is carried out next.

2.4. Parametric characterization

The MWS microstrip structure is characterized in terms of its effective permittivity and permeability parameters, \(\varepsilon_{\text{eff}}\) and \(\mu_{\text{eff}}\) versus frequency as a function of the diameter of the wires and of the structured substrate height \(h_2\), which are the most significant parameters in terms of variations of the \(\varepsilon_{\text{eff}}\) and \(\mu_{\text{eff}}\). The results are presented in Fig. 5 and 6, and may be used as charts for designs.

![Comparison of epsilon extraction](image1)

(a) Extracted \(\varepsilon_{\text{eff}}\)

![Comparison of mu extraction](image2)

(b) Extracted \(\mu_{\text{eff}}\)

Figure 4. Metallic wire substrate (MWS) microstrip transmission line prototype parameters compared to those of a MoM-simulated 50\(\Omega\) TL on a regular substrate computed by (5) and (6).

Figure 5. Effect of the variation of via holes diameter on the \(\varepsilon_{\text{eff}}\) and \(\mu_{\text{eff}}\) parameters.
From a conventional Duroid host substrate with permittivity $\varepsilon_r = 2.94$, an MWS’s with values of $\varepsilon_{\text{eff}}$ ranging from 4 to 9 and of $\mu_{\text{eff}}$ ranging from 1.3 to 2 have been achieved using parameters that are currently available with the laser-drilling and holes-plating technology at the Poly-Grames Research Center.

The MWS provides novel possibility for the design of planar circuits on substrate with arbitrary permittivity and permeability over a large range of values. In addition, it allows the miniaturization of planar circuits and antennas thanks to its enhanced refractive index compared to that of the host substrate.

3. APPLICATION: METALLIC WIRE SUBSTRATE (MWS) MICROSTRIP PATCH ANTENNA

As an application of the MWS presented in the previous section, the inset-fed MWS patch antenna shown in Fig.7(a) was designed and compared with the corresponding microstrip patch antenna on a homogeneous substrate ($\varepsilon_r = 2.94$) [Fig. 7(b)] for the same resonant frequency, which has been chosen as 1.9 GHz.

Since the resonant size of the antenna is $L \cong \frac{\lambda_g}{2} = \frac{\lambda_g}{2n}$, the size of the antenna can be significantly reduced via the enhanced refractive index of the MWS $n = \sqrt{\varepsilon_{\text{eff}} \mu_{\text{eff}}}$.

The simulated return loss of the MWS antenna with the effective parameters extracted in Fig. 4 compared with that of the homogeneous substrate antenna with same resonance frequency is presented in Fig. 8.

The simulated radiation patterns of the MWS antenna compared with those of the homogeneous substrate antenna are shown in Fig. 9.
Figure 9. Simulated co and cross radiation patterns in the E-plane (E-p) and H-plane (H-p).

In Tab. 1, the principle parameters of the antenna are presented.

<table>
<thead>
<tr>
<th>f = 1.9 GHz</th>
<th>MWS (ε_{eff} = 4.8, µ_{eff} = 1.3)</th>
<th>Homogeneous substrate (ε_r = 2.94)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Dimension</td>
<td>L = 32.3 mm L = 46.3 mm</td>
<td></td>
</tr>
<tr>
<td>Gain</td>
<td>5.5 dBi</td>
<td>5.8 dBi</td>
</tr>
</tbody>
</table>

Table 1. Parameters comparison for the MWS and homogeneous substrate antenna

The MWS microstrip patch antenna exhibits a 30% size (resonant length) reduction compared to the patch antenna on a conventional substrate, with similar return loss (~ 20 dB) and co-cross polarization isolation (~ 40 dB). Tab. 1 shows that the size reduction (and subsequent directivity reduction due to reduced aperture) has not been done at the expense of significant gain reduction, which suggests that the efficiency of the homogeneous antenna could be preserved. This is most likely due to the fact that the permeability is increased at the same time as the permittivity, which keeps the input impedance of the antenna almost unchanged.

4. CONCLUSION

This paper has presented a characterization of the metallic wire substrate (MWS) in terms of its effective permittivity ε_{eff} and permeability µ_{eff} and the application of the MWS to a microstrip patch antenna.

It has been shown by way of full-wave simulations that the MWS exhibits artificial magneto-dielectric properties with simultaneously enhanced effective permittivity and permeability over a large frequency band. An MWS microstrip line structure with values of ε_{eff} ranging from 4 to 9 and of µ_{eff} ranging from 1.3 to 2, respectively, has been achieved. A size reduction of 30% without significant gain reduction has been achieved in the MWS microstrip antenna.

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